

## ST300S SERIES

### PHASE CONTROL THYRISTORS

### Stud Version

300A

#### Features

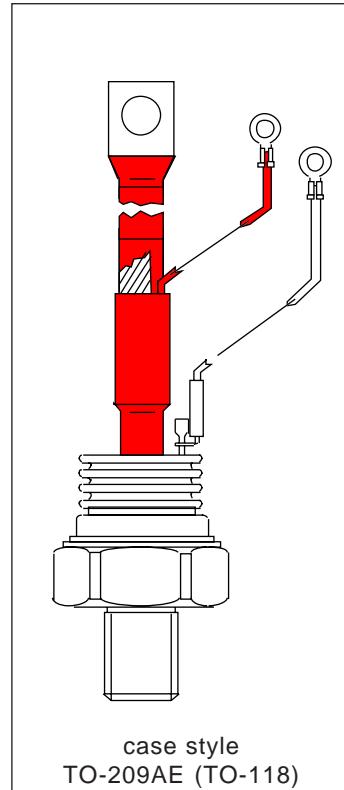
- Center amplifying gate
- Hermetic metal case with ceramic insulator
- International standard case TO-209AE (TO-118)
- Threaded studs UNF 3/4 - 16UNF2A or ISO M24x1.5
- Compression Bonded Encapsulation for heavy duty operations such as severe thermal cycling

#### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

#### Major Ratings and Characteristics

| Parameters        | ST300S      | Units             |
|-------------------|-------------|-------------------|
| $I_{T(AV)}$       | 300         | A                 |
| @ $T_c$           | 75          | °C                |
| $I_{T(RMS)}$      | 470         | A                 |
| $I_{TSM}$         | 8000        | A                 |
| @ 50Hz            | 8000        | A                 |
| @ 60Hz            | 8380        | A                 |
| $I^2t$            | 320         | KA <sup>2</sup> s |
| @ 50Hz            | 320         | KA <sup>2</sup> s |
| @ 60Hz            | 292         | KA <sup>2</sup> s |
| $V_{DRM}/V_{RRM}$ | 400 to 2000 | V                 |
| $t_q$             | typical 100 | μs                |
| $T_j$             | - 40 to 125 | °C                |



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Bulletin I25158 rev. B 01/94

International  
**IR** Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

| Type number | Voltage Code | $V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V | $V_{RSM}$ , maximum non-repetitive peak voltage V | $I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J \max}$ mA |
|-------------|--------------|--|---|--|
| ST300S      | 04           | 400  | 500   | 50   |
|             | 08           | 800  | 900   |  |
|             | 12           | 1200   | 1300  |  |
|             | 16           | 1600   | 1700  |  |
|             | 18           | 1800   | 1900  |  |
|             | 20           | 2000   | 2100  |  |

#### On-state Conduction

| Parameter   | ST300S | Units              | Conditions  |
|---|--------|--------------------|---|
| $I_{T(AV)}$<br>@ Case temperature                                 | 300    | A                  | 180° conduction, half sine wave   |
|   | 75     | °C                 |   |
| $I_{T(RMS)}$  | 470    | A                  | DC @ 64°C case temperature  |
| $I_{TSM}$<br>Max. peak, one-cycle<br>non-repetitive surge current | 8000   | A                  | t = 10ms<br>t = 8.3ms<br>100% $V_{RRM}$<br>reapplied                                    |
|   | 8380   |                    |   |
|   | 6730   |                    |   |
|   | 7040   |                    |   |
| $I^2t$<br>Maximum $I^2t$ for fusing                               | 320    | KA <sup>2</sup> s  | t = 10ms<br>t = 8.3ms<br>100% $V_{RRM}$<br>reapplied                                    |
|   | 292    |                    |   |
|   | 226    |                    |   |
|   | 207    |                    |   |
| $I^2/\tau$  | 3200   | KA <sup>2</sup> /s | t = 0.1 to 10ms, no voltage reapplied   |
| $V_{T(TO)1}$<br>Low level value of threshold voltage              | 0.97   | V                  | (16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$ . |
| $V_{T(TO)2}$<br>High level value of threshold voltage             | 0.98   |                    | ( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$ .                                    |
| $r_{t1}$<br>Low level value of on-state slope resistance          | 0.74   | mΩ                 | (16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$ . |
| $r_{t2}$<br>High level value of on-state slope resistance         | 0.73   |                    | ( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$ .                                    |
| $V_{TM}$<br>Max. on-state voltage                                 | 1.66   | V                  | $I_{pk} = 940A$ , $T_J = T_{J \max}$ , $t_p = 10ms$ sine pulse                          |
| $I_H$<br>Maximum holding current                                  | 600    | mA                 | $T_J = 25^\circ C$ , anode supply 12V resistive load                                    |
| $I_L$<br>Typical latching current                                 | 1000   |                    |   |

### Switching

| Parameter   | ST300S | Units | Conditions  |
|---|--------|-------|---|
| di/dt Max. non-repetitive rate of rise of turned-on current | 1000   | A/μs  | Gate drive 20V, 20Ω, $t_r \leq 1\mu s$<br>$T_J = T_{J\max}$ , anode voltage $\leq 80\% V_{DRM}$                                 |
| $t_d$ Typical delay time                                    | 1.0    | μs    | Gate current 1A, $d_i_g/dt = 1A/\mu s$<br>$V_d = 0.67\% V_{DRM}$ , $T_J = 25^\circ C$   |
| $t_q$ Typical turn-off time                                 | 100    |       | $I_{TM} = 550A$ , $T_J = T_{J\max}$ , $di/dt = 40A/\mu s$ , $V_R = 50V$<br>$dv/dt = 20V/\mu s$ , Gate 0V 100Ω, $t_p = 500\mu s$ |

### Blocking

| Parameter   | ST300S | Units | Conditions  |
|---|--------|-------|---|
| dv/dt Maximum critical rate of rise of off-state voltage          | 500    | V/μs  | $T_J = T_{J\max}$ linear to 80% rated $V_{DRM}$     |
| $I_{RRM}/I_{DRM}$ Max. peak reverse and off-state leakage current | 50     | mA    | $T_J = T_{J\max}$ , rated $V_{DRM}/V_{RRM}$ applied |

### Triggering

| Parameter                                    | ST300S                   | Units                 | Conditions   |
|--|--------------------------|-----------------------|--|
| $P_{GM}$ Maximum peak gate power             | 10.0                     | W                     | $T_J = T_{J\max}$ , $t_p \leq 5ms$   |
| $P_{G(AV)}$ Maximum average gate power       | 2.0                      |                       | $T_J = T_{J\max}$ , $f = 50Hz$ , $d\% = 50$  |
| $I_{GM}$ Max. peak positive gate current     | 3.0                      | A                     | $T_J = T_{J\max}$ , $t_p \leq 5ms$   |
| $+V_{GM}$ Maximum peak positive gate voltage | 20                       | V                     | $T_J = T_{J\max}$ , $t_p \leq 5ms$   |
| $-V_{GM}$ Maximum peak negative gate voltage | 5.0                      |                       |  |
| $I_{GT}$ DC gate current required to trigger | TYP.<br>200<br>100<br>50 | MAX.<br>-<br>200<br>- | mA $T_J = -40^\circ C$<br>$T_J = 25^\circ C$<br>$T_J = 125^\circ C$ Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied |
| $V_{GT}$ DC gate voltage required to trigger | 2.5<br>1.8<br>1.1        | -<br>3<br>-           | V $T_J = -40^\circ C$<br>$T_J = 25^\circ C$<br>$T_J = 125^\circ C$   |
| $I_{GD}$ DC gate current not to trigger      | 10.0                     | mA                    |  |
| $V_{GD}$ DC gate voltage not to trigger      | 0.25                     | V                     | $T_J = T_{J\max}$ Max. gate current/ voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied                                    |

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### Thermal and Mechanical Specification

| Parameter  | ST300S                                       | Units             | Conditions     |
|------------|--|-------------------|----------------|
| $T_J$      | Max. operating temperature range             | -40 to 125        | °C             |
| $T_{sg}$   | Max. storage temperature range               | -40 to 150        |                |
| $R_{thJC}$ | Max. thermal resistance,<br>junction to case | 0.10              | K/W            |
| $R_{thCS}$ | Max. thermal resistance,<br>case to heatsink | 0.03              |                |
| T          | Mounting torque, $\pm 10\%$                  | 48.5<br>(425)     | Nm<br>(lbf-in) |
| wt         | Approximate weight                           | 535               | g              |
| Case style | TO - 209AE (TO-118)                          | See Outline Table |                |

### $\Delta R_{thJC}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC)

| Conduction angle | Sinusoidal conduction | Rectangular conduction | Units | Conditions                 |
|------------------|-----------------------|------------------------|-------|----------------------------|
| 180°             | 0.011                 | 0.008                  | K/W   | $T_J = T_{J \text{ max.}}$ |
| 120°             | 0.013                 | 0.014                  |       |                            |
| 90°              | 0.017                 | 0.018                  |       |                            |
| 60°              | 0.025                 | 0.026                  |       |                            |
| 30°              | 0.041                 | 0.042                  |       |                            |

### Ordering Information Table

| Device Code | ST  | 30 | 0 | S | 20 | P | 0 |   |
|-------------|---|----|---|---|----|---|---|---|
|             | 1   | 2  | 3 | 4 | 5  | 6 | 7 | 8 |
| <b>1</b>    | - Thyristor   |    |   |   |    |   |   |   |
| <b>2</b>    | - Essential part number   |    |   |   |    |   |   |   |
| <b>3</b>    | - 0 = Converter grade   |    |   |   |    |   |   |   |
| <b>4</b>    | - S = Compression bonding Stud                                    |    |   |   |    |   |   |   |
| <b>5</b>    | - Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table) |    |   |   |    |   |   |   |
| <b>6</b>    | - P = Stud base 16UNF threads                                     |    |   |   |    |   |   |   |
|             | M = Stud base metric threads (M24 x 1.5)                          |    |   |   |    |   |   |   |
| <b>7</b>    | - 0 = Eyelet terminals (Gate and Auxiliary Cathode Leads)         |    |   |   |    |   |   |   |
|             | 1 = Fast - on terminals (Gate and Auxiliary Cathode Leads)        |    |   |   |    |   |   |   |
|             | 3 = Threaded top terminal 3/8" 24UNF-2A                           |    |   |   |    |   |   |   |
| <b>8</b>    | - Critical dv/dt: None = 500V/ $\mu$ sec (Standard value)         |    |   |   |    |   |   |   |
|             | L = 1000V/ $\mu$ sec (Special selection)                          |    |   |   |    |   |   |   |

Outline Table

